

INFORMATION DISCLOSURE CITATION (USE SEVERAL SHEETS IF NECESSARY)				Complete if Known			
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				First Named Inventor	Christian DUSSARRAT		
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				Examiner Name	Elizabeth A. Burkhart		
Sheet	1	of	1	Attorney Docket Number	Serie 6070		
U.S. PATENT DOCUMENTS							
Examiner Initials	Cite No.	Document Number	Publication Date	Name	Pages Column, Lines Where Relevant Passages or Relevant Figures Appear		
	A1	US 5 932 286	8/03/1999	BEINGLASS et al.			
FOREIGN PATENT DOCUMENTS							
Examiner Initials	Cite No.	Document Number	Publication Date	Name	Pages Column, Lines Where Relevant Passages or Relevant Figures Appear		
NON PATENT LITERATURE DOCUMENTS							
Examiner Initials	Cite No.	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published					T
	C1	PEREIRA, M.A. et al., "Silicon nitride deposited by ECR-CVD at room temperature for LOCOS isolation technology," Applied Surface Science 212-213 (2003), pp. 388-392					
	C2	YOTA, J. et al., "A comparative study on inductively-coupled plasma high-density plasma, plasma-enhanced, and low pressure chemical vapor deposition silicon nitride films," J. Vac. Sci. Technol. A 18(2), Mar/Apr 2000, pp. 372-376					
Examiner				Date Considered			
/Elizabeth Burkhart/				03/31/2011			
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